

Solvation

CHEM8711/7711

Solvent Influence

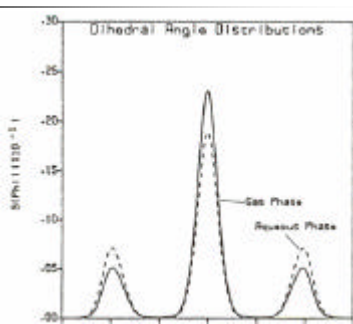
- Solvent influence levels
 - Direct interaction (or reaction) with solute
 - Solvent provides environment (anisotropic, for example) that influences solute behavior (mean field effect)
 - Solvent acts as bulk medium affecting solute properties

CHEM8711/7711:

2

Bulk Solvent Effect Example

Butane
Conformation
Distribution



CHEM8711/7711:

3

Solvation Treatment

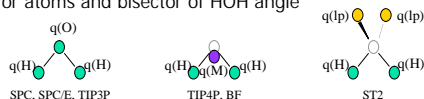
- Explicit
 - System includes actual solvent molecules
 - Required for any direct solvent-solute interaction
 - Problems
 - System becomes quite large if long-range effects are to be handled well
 - Sampling of solvent configurations required
 - Simulation times increase
- Implicit
 - System does not include actual solvent molecules

CHEM8711/7711:

4

Explicit Water Models

- Simple Pairwise Potentials
 - Interaction sites defined on atoms, atoms and lone pairs, or atoms and bisector of HOH angle



- VDW interactions may be simplified to one per pair of water molecules
- Individual molecule dipole moments (~2.25D) approximate liquid water (2.6D) rather than gas phase (1.85D)

- Polarizable

CHEM8711/7711:

5

Implicit Solvent Models

- Dielectric Screening
- Continuum Representations
 - Attempt to represent three contributions to solvation free energy:

$$\Delta G_{\text{sol}} = \Delta G_{\text{elec}} + \Delta G_{\text{vdw}} + \Delta G_{\text{cav}}$$

- Widely used methods addressing ΔG_{elec} :
 - Born model (we will discuss generalized Born model, which also addresses ΔG_{vdw} and ΔG_{cav})
 - Poisson-Boltzmann

CHEM8711/7711:

6

Dielectric Screening

- Polar solvents screen (reduce) electrostatic interactions

- Electrostatic function:
$$V = \frac{q_1 q_2}{Dr}$$

- Common solvent dielectric constants:
 - gas phase: 1
 - water: 78.3
 - alkanes: 3
 - aqueous/membrane interface: 10

CHEM8711/7711:

7

Limitation

- The influence of solvent includes an electrostatic and an entropic contribution
 - The electrostatic component is due to solvent polarization (and screening of charge interactions due to intervening solvent molecules)
 - Entropic contributions are due to formation of solvent cavities around solutes
 - The solvent dielectric only reflects the screening of charge interactions

CHEM8711/7711:

8

Class Exercise

- Compute the conformational populations for either butane or 1,4-butanedione (coordinate with another student to make sure both are covered) with the solvent dielectric set to 1
- Recompute the conformational populations with the solvent dielectric set to 80

if you have a database of conformations, you can reset the dielectric using Window->Potential Control and then get energies for re-minimized structures:

```
db_ComputeEnergy ['database.mdb','source field','destination field',1]
```

CHEM8711/7711:

9

Exercise Analysis

- Consider the following questions:
 - Are the lowest energy conformations the same with different solvent dielectrics?
 - If not, how do they differ (structurally)?

CHEM8711/7711:

10

Generalized Born Method

- Solvation free energies can be expressed as a sum of a solvent cavity term, a solvent-solute van der Waals term and an electrostatic polarization term

$$G_{\text{sol}} = G_{\text{cav}} + G_{\text{VDW}} + G_{\text{pol}}$$

- The cavity and van der Waals terms are related to the solvent-accessible surface area

$$G_{\text{cav}} + G_{\text{VDW}} = \sum_k \sigma_k S A_k$$

parameter for atom type k solvent accessible surface area for atoms of type k

- Electrostatic term form:

$$\Delta G_{\text{elec}} = -\frac{1}{2} \left(1 - \frac{1}{\epsilon} \right) \sum_{j=1}^N \sum_{i=1}^N \frac{q_i q_j}{f(r_{ij}, a_{ij})}$$

Interparticle distance Born radii

CHEM8711/7711:

11

Implicit Solvation of Butane

	$\epsilon=1$	$\epsilon=80$
Anti	23.4317 (99.98421%)	25.6143 (99.98420%)
Gauche ⁺	24.3669 (0.00789%)	26.5494 (0.00790%)
Gauche ⁻	24.3669 (0.00789%)	26.5494 (0.00790%)

Changes in conformational distribution due to solvation of hydrophobic molecules are largely NOT electrostatic in nature

CHEM8711/7711:

12

GB/SA Results for Butane

	No Solvent	GB/SA water
Anti	-5.076 (99.92605%)	-3.04947 (99.88116%)
Gauche ⁺	-4.29374 (0.03697%)	-2.31422 (0.05942%)
Gauche ⁻	-4.29374 (0.03697%)	-2.31422 (0.05942%)

Inclusion of the cavity and van der Waals effects of solvation improves the calculated influence of solvent

CHEM8711/7711:

13

Poisson Equation

$$\underbrace{\nabla^2 f(r)}_{\text{Variation in potential } (\phi)} = - \underbrace{4\pi r(r)}_{\substack{\text{Charge density} \\ \mathbf{e} \\ \text{Medium constant dielectric}}}$$

$$\underbrace{\nabla \cdot \mathbf{e}(r)}_{\text{Dielectric field varies with position}} \nabla f(r) = -4\pi r(r)$$

CHEM8711/7711:

14

Boltzmann Distribution of Ions

$$n(r) = N \exp\left(\frac{-\mathbf{u}(r)}{k_B T}\right)$$

Number density of ions at r
Bulk number density

Energy change of ion transfer from infinity to r

CHEM8711/7711:

15

Linearized Poisson-Boltzmann Equation

$$\nabla \cdot \mathbf{e}(r) \nabla f(r) - k' f(r) = -4\pi r(r)$$

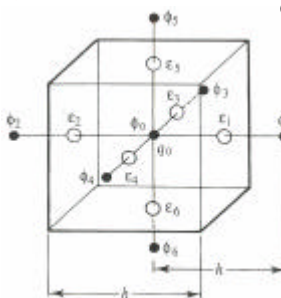
$$k' = \frac{8pN_A e^2 I}{1000k_B T}$$

- Must be solved numerically

CHEM8711/7711:

16

Finite Difference Method



Constant charge density in cube:

$$r_0 = \frac{q_0}{h^3}$$

Potential at grid point 0:

$$f_0 = \frac{\sum \mathbf{e}_i f_i + 4\pi r_0 \frac{q_0}{h}}{\sum \mathbf{e}_i + k_0^2}$$

potential influenced by surrounding grid points – iterate until consistent solution achieved

CHEM8711/7711:

17

Reading

- Chapter 4, section 14
- Chapter 11, sections 9-12

CHEM8711/7711:

18